

General Description

The SY81153C high efficiency 1200kHz synchronous buck converter operates over a wide input voltage range of 4V to 18V, and can deliver an output current up to 3A. It integrates a top MOSFET and a bottom MOSFET with very low $R_{DS(ON)}$ to minimize conduction loss. The 1200kHz pseudo-constant switching frequency enables using small external inductor and capacitor values.

The SY81153C uses constant on-time and ripple-based control strategy to achieve fast transient response for applications with variable duty cycle, and high efficiency at light loads. It also provides cycle-by-cycle current limit protection, output under voltage protection and over temperature protection.

Only the input and output capacitors, inductor, feedback resistor divider and feedforward capacitor need to be selected for the targeted application specifications.

The SY81153C is available in a compact SOT563 package.

Features

- Low $R_{DS(ON)}$ for Internal MOSFETs: 65m Ω Top, 30m Ω Bottom
- Wide Input Voltage Range: 4V ~ 18V
- Up to 3A Output Current
- Precise $\pm 1\%$ 0.6V Reference under $-40^{\circ}\text{C} \sim 125^{\circ}\text{C}$
- Precise EN Threshold
- PFM Light Load Operation for High Efficiency
- Internal Soft-Start Limits the Inrush Current
- 1200kHz Switching Frequency Minimizes the External Components
- Constant On-time and Ripple-Based Control to Achieve Fast Transient Responses
- Cycle-by-Cycle Valley and Peak Current Limit Protection
- Hic-Cup Mode Output Under Voltage Protection
- Auto-Recovery Mode Over Temperature Protection
- Input Under Voltage Lockout (UVLO)
- RoHS-Compliant and Halogen-Free
- Compact Package: SOT563
- Moisture Sensitivity Level (MSL): 1

Applications

- Set Top Box
- Portable TV
- DSL Modem
- LCD TV
- IP Camera
- Networking

Typical Application

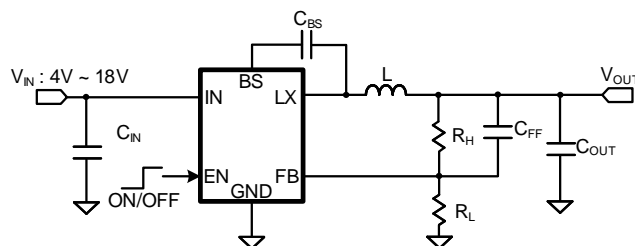


Figure1. Schematic Diagram
Inductor and C_{OUT} Selectin Table

$V_{OUT}[V]$	$L[\mu H]$	$C_{OUT}[\mu F]$			
		10	22	32	44
1.2	1			√	☆
	1.5			√	√
1.8	1		√	√	√
	1.5		√	√	☆
3.3	1.5		√	√	√
	2.2		√	√	☆
5	2.2		√	√	√
	3.3		√	√	☆

Note: '☆' means recommended for most applications.

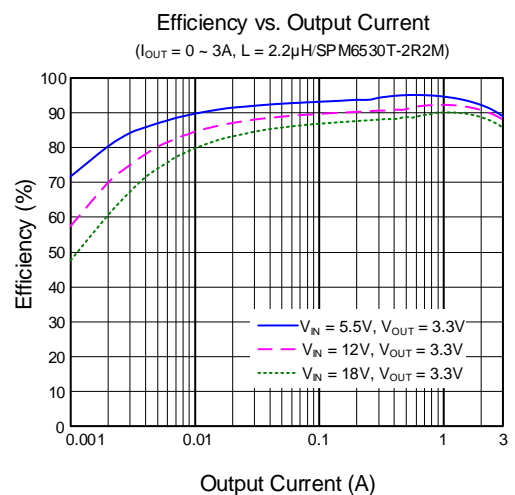


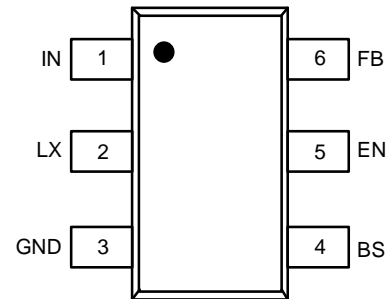
Figure2. Efficiency vs. Output Current

Ordering Information

Ordering Part Number	Package Type	Top Mark
SY81153CART	SOT563 RoHS Compliant and Halogen Free	HRQxyz

x = year code, y = week code, z = lot number code

Pinout (top view)



Pin Description

Pin No	Pin Name	Pin Description
1	IN	Input pin. Decouple this pin from the GND pin with at least a 10 μ F ceramic capacitor.
2	LX	Inductor pin. Connect this pin to the switching node of inductor.
3	GND	Ground pin.
4	BS	Bootstrap pin. Supply top MOSFET gate driver. Connect a 0.1 μ F ceramic capacitor and between BS and LX pin.
5	EN	Enable pin. Pull this pin higher than EN rising threshold to turn on the device and pull this pin lower than EN falling threshold to turn off the device. Do not leave this pin floating.
6	FB	Output feedback pin. Connect this pin to the center point of the output resistor divider as shown in Figure 1. $V_{OUT} = 0.6 \times (1 + R_H/R_L)$.



Block Diagram

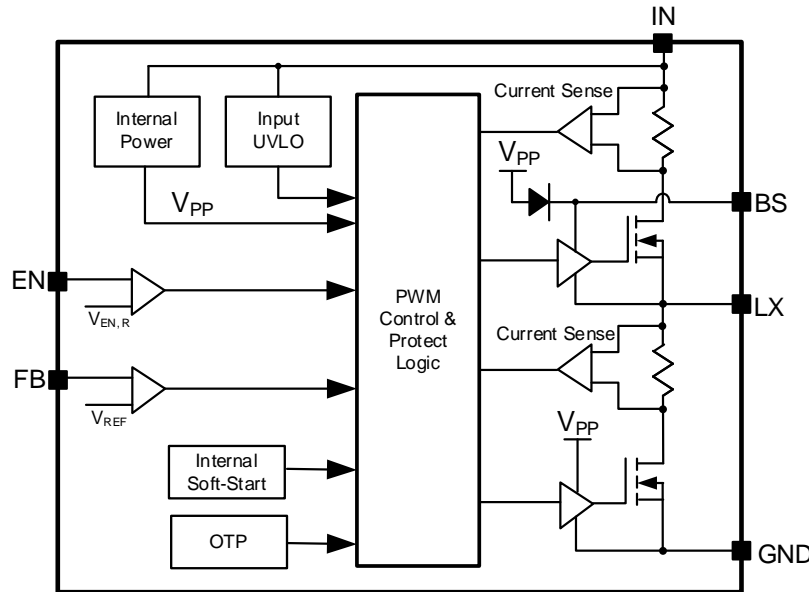


Figure3. Block Diagram

Absolute Maximum Ratings

Parameter (Note 1)	Min	Max	Unit
IN	-0.3	19	V
EN, LX	-0.3	IN + 0.3	
LX, 10ns Duration	GND - 4	IN + 3	
LX, 20ns Duration	GND - 1	IN + 1	
BS	LX - 0.3	LX + 4	
FB	-0.3	4	
Junction Temperature, Operating	-40	150	°C
Lead Temperature (Soldering, 10s)		260	
Storage Temperature	-65	150	

Thermal Information

Parameter (Note 2)	Typ	Unit
θ_{JA} Junction-to-Ambient Thermal Resistance	70	°C/W
θ_{JC} Junction-to-Case Thermal Resistance	8	
P_D Power Dissipation $T_A = 25^\circ\text{C}$	1.4	W

Recommended Operating Conditions

Parameter (Note 3)	Min	Max	Unit
Input Voltage	4	18	V
Output Voltage	0.6	9.2	
Continuous Output Current		3	A
Junction Temperature, Operating	-40	125	°C
Ambient Temperature	-40	85	



Electrical Characteristics

(V_{IN} = 12V, V_{OUT} = 3.3V, L = 2.2μH, C_{OUT} = 44μF, T_J = 25°C, I_{OUT} = 1A unless otherwise specified (Note 4))

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit	
Input	Voltage Range	V _{IN}	4		18	V	
	UVLO Rising Threshold	V _{IN,UVLO}	V _{IN} rising		3.95		
	UVLO Hysteresis	V _{IN,HYS}		0.3			
	Shutdown Current	I _{SHDN}	V _{EN} = 0V	5	10	μA	
	Quiescent Current	I _Q	I _{OUT} = 0A, EN = High, V _{FB} = V _{REF} × 105%		160		
Output	Voltage Range	V _{SET}	0.6		9.2	V	
	FB Reference Voltage	V _{REF}	T _J = -40°C ~ 125°C	0.594	0.6		0.606
	FB Input Current	I _{FB}	V _{FB} = 1V	-50		50	nA
	Turn On Delay Time	t _{ON,DLY}	From EN high to LX starts switching(Note 5)		300		μs
	Soft-Start Time	t _{SS}	V _{OUT} from 0% to 100% V _{SET}		1.5		ms
	UVP Threshold	V _{UVP}			33		%V _{REF}
	UVP Delay Time	t _{UVP,DLY}			100		μs
	UVP Hiccup On-Time	t _{UVP,ON}			2.5		ms
	UVP Hiccup Off-Time	t _{UVP,OFF}			7.5		
Enable (EN)	Rising Threshold	V _{EN,R}	1.14	1.2	1.26	V	
	Falling Threshold	V _{EN,F}	1.04	1.1	1.16		
	Internal Resistor to GND	R _{EN}			1		MΩ
MOSFET	Top MOSFET R _{DS(ON)}	R _{DS(ON),TOP}		65		mΩ	
	Bottom MOSFET R _{DS(ON)}	R _{DS(ON),BOT}		30			
	Top MOSFET Current Limit Threshold	I _{LMT,TOP}		4.5		A	
	Bottom MOSFET Current Limit Threshold	I _{LMT,BOT}		3.5			
Frequency	Switching Frequency	f _{SW}	I _{OUT} = 1A, CCM		1200		kHz
	Minimum On-Time	t _{ON,MIN}			50		ns
	Minimum Off-Time	t _{OFF,MIN}			200		
OTP	Temperature	T _{OTP}	(Note 5)		150		°C
	Temperature Hysteresis	T _{HYS}	(Note 5)		15		

Note 1: Stresses beyond the “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 2: θ_{JA} is measured in the natural convection at T_A = 25°C on a 6cm×6cm size, two-layer Silergy Evaluation Board with 2-oz copper. Pin 2 of SOT563 package is the case position for θ_{JC} measurement.

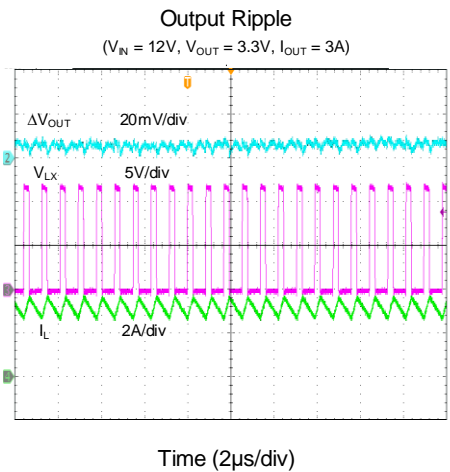
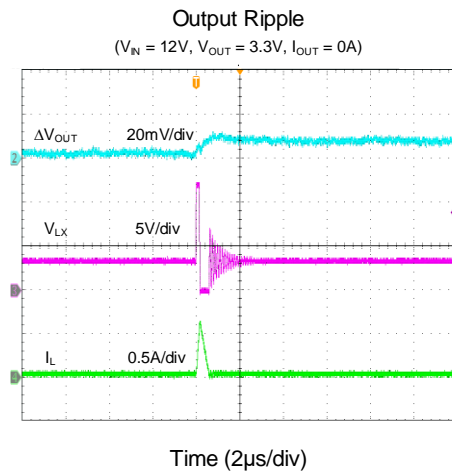
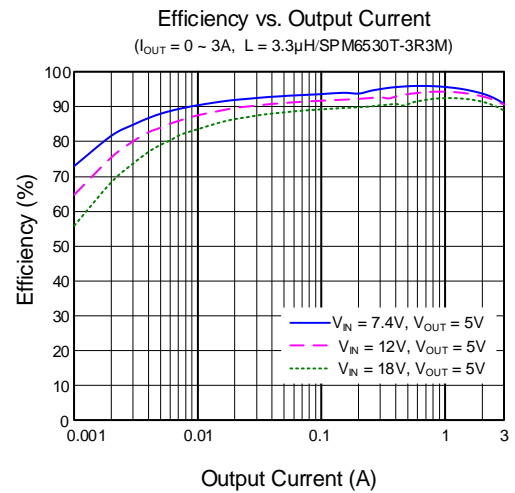
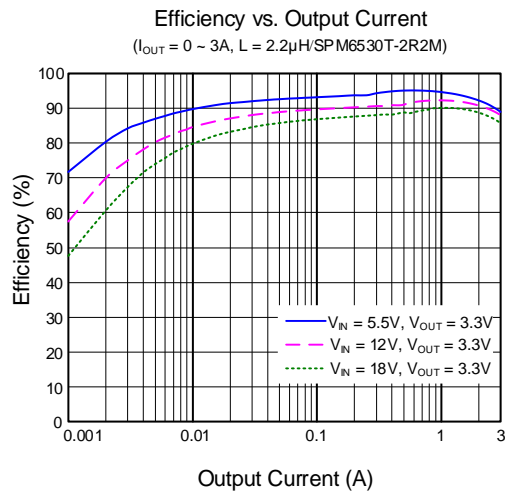
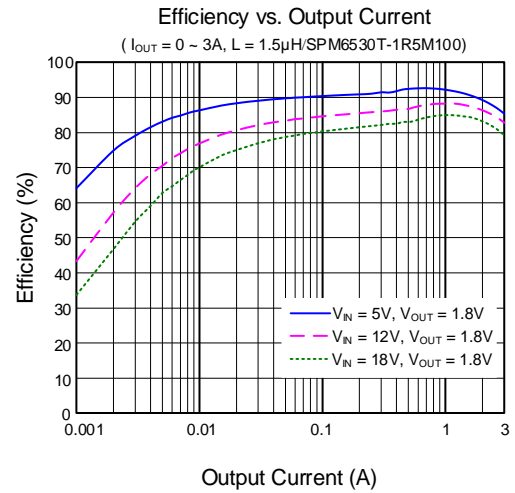
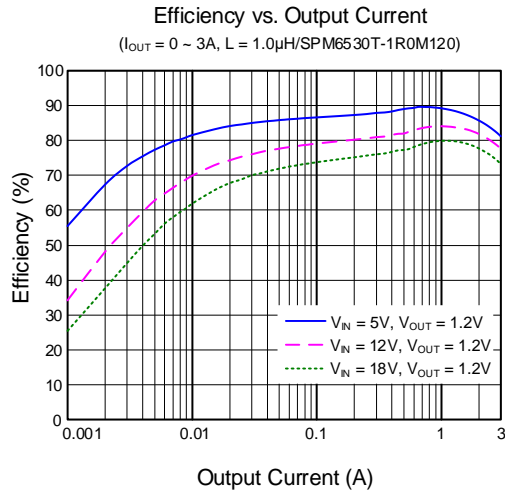
Note 3: The device is not guaranteed to function outside its operating conditions.

Note 4: Unless otherwise stated, limits are 100% production tested under pulsed load conditions such that T_A ≅ T_J = 25°C. Limits over the operating temperature range (See recommended operating conditions) and relevant voltage range(s) are guaranteed by design, test, or statistical correlation.

Note 5: Guaranteed by design or statistical correlation and not production tested.

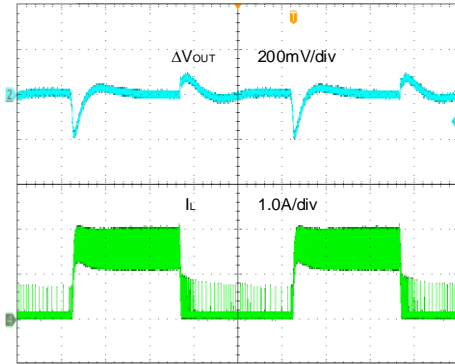
Typical Performance Characteristics

($T_A = 25^\circ\text{C}$, $V_{IN} = 12\text{V}$, $V_{OUT} = 3.3\text{V}$, $L = 2.2\mu\text{H}$, $C_{OUT} = 44\mu\text{F}$, unless otherwise noted)



Load Transient

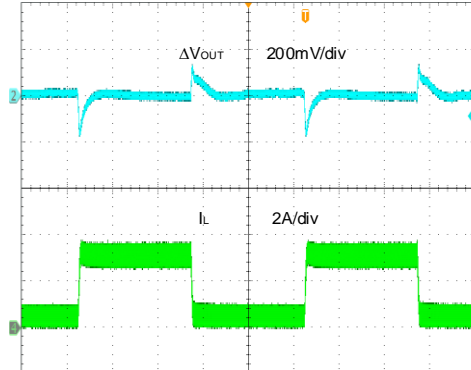
($V_{IN} = 12V$, $V_{OUT} = 3.3V$, $I_{OUT} = 0A \sim 1.5A$)



Time (200µs/div)

Load Transient

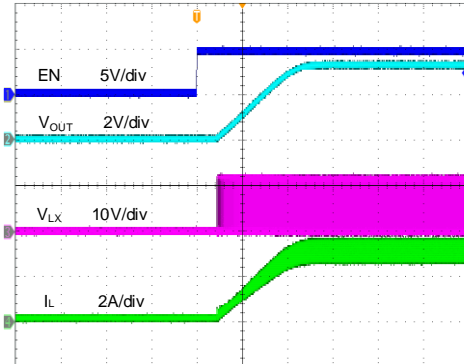
($V_{IN} = 12V$, $V_{OUT} = 3.3V$, $I_{OUT} = 0.3A \sim 3A$)



Time (200µs/div)

Startup from Enable

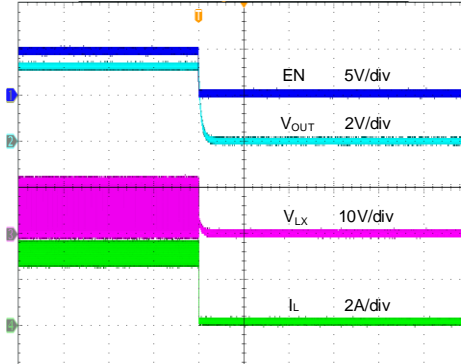
($V_{IN} = 12V$, $V_{OUT} = 3.3V$, $I_{OUT} = 3A$)



Time (800µs/div)

Shutdown from Enable

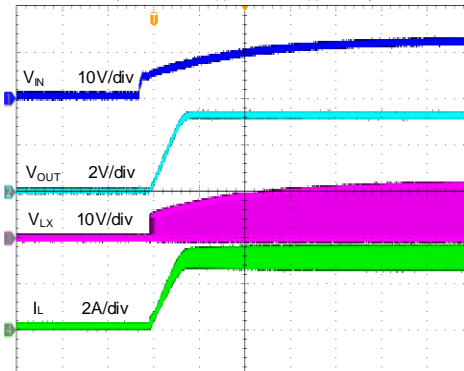
($V_{IN} = 12V$, $V_{OUT} = 3.3V$, $I_{OUT} = 3A$)



Time (800µs/div)

Startup from VIN

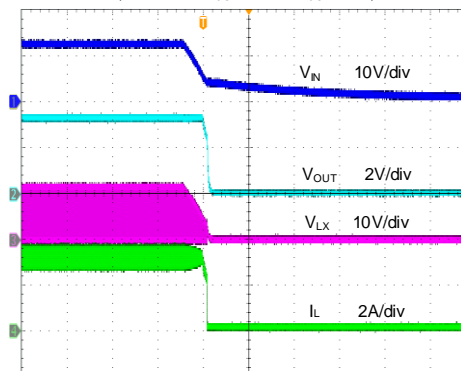
($V_{IN} = 12V$, $V_{OUT} = 3.3V$, $I_{OUT} = 3A$)



Time (2ms/div)

Shutdown from VIN

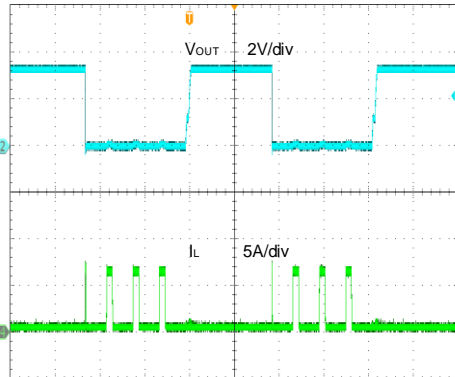
($V_{IN} = 12V$, $V_{OUT} = 3.3V$, $I_{OUT} = 3A$)



Time (2ms/div)

Short Circuit Protection

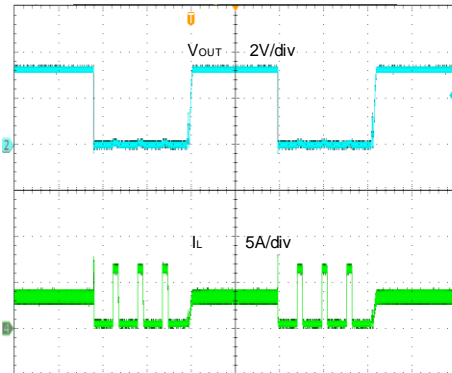
($V_{IN} = 12V, V_{OUT} = 3.3V, I_{OUT} = 0A \sim \text{short}$)



Time (20ms/div)

Short Circuit Protection

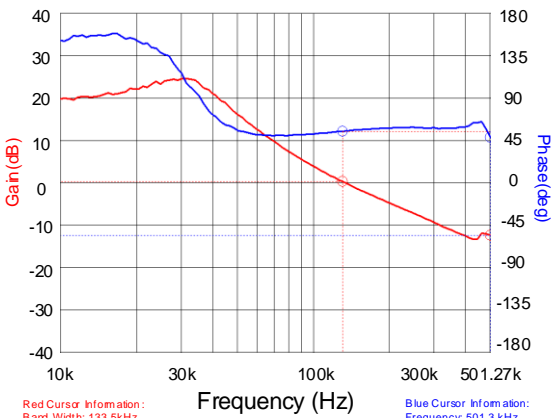
($V_{IN} = 12V, V_{OUT} = 3.3V, I_{OUT} = 3A \sim \text{short}$)



Time (20ms/div)

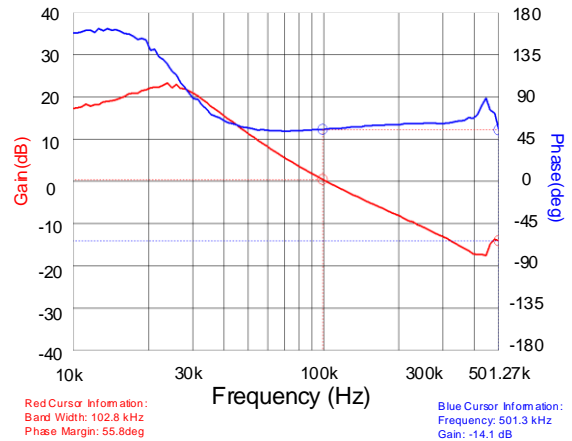
Bode Plot

($V_{IN} = 12V, V_{OUT} = 1.2V, I_{OUT} = 3A$)



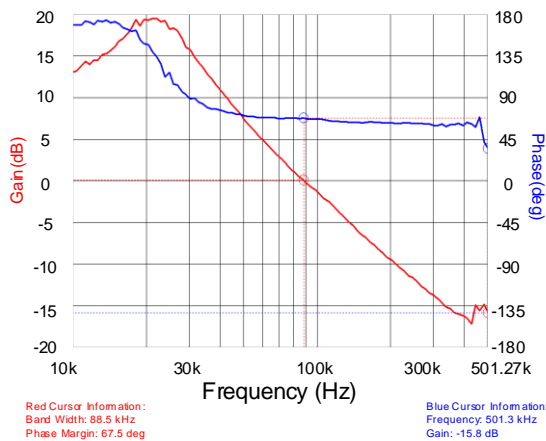
Bode Plot

($V_{IN} = 12V, V_{OUT} = 1.8V, I_{OUT} = 3A$)



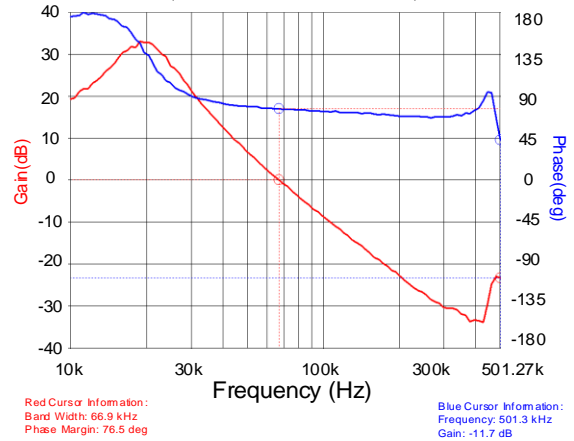
Bode Plot

($V_{IN} = 12V, V_{OUT} = 3.3V, I_{OUT} = 3A$)



Bode Plot

($V_{IN} = 12V, V_{OUT} = 5V, I_{OUT} = 3A$)



Detailed Description

General Description

The SY81153C high efficiency 1200kHz synchronous buck converter operates over a wide input voltage range of 4V to 18V, and can deliver an output current up to 3A. It integrates a top MOSFET and a bottom MOSFET with very low $R_{DS(ON)}$ to minimize conduction loss. The 1200kHz pseudo-constant switching frequency allows small external inductor and capacitor values.

The SY81153C also provides cycle-by-cycle current limit protection, output under voltage protection and over temperature protection.

Constant On-Time and Ripple-Based Control Strategy

The device uses instant PWM architecture to achieve fast transient response for applications with high step-down ratios, and high efficiency at light loads. It uses a constant on-time and ripple-based control strategy in which a virtual replica of the inductor current signal is synthesized internally and combined with the feedback voltage. When the sum voltage is lower than the reference voltage, the bottom MOSFET turns off and the top MOSFET turns on for a fixed period of time (Constant t_{ON}). t_{ON} is internally calculated according to the input voltage, output voltage, and desired switching frequency (f_{SW}):

$$t_{ON} = \frac{V_{OUT}/V_{IN}}{f_{SW}}$$

The top MOSFET turns off after a period of t_{ON} .

Minimum and Maximum Duty Cycle

In the COT architecture, there is no limitation for operating the part at low duty cycle, since in this case, when the on-time is close to the minimum on-time, the switching frequency is reduced as needed to always ensure a proper operation.

The device can support a maximum duty cycle of up to 60% across the entire operating temperature range of -40°C ~ 125°C .

Light Load Operation

The device uses pulse-frequency modulation (PFM) operation mode under light load condition for high efficiency. Under light load conditions, typically when the load satisfies the following equation,

$$I_{OUT_CTL} = \frac{\Delta I_L}{2} = \frac{V_{OUT} \times (1 - D)}{2 \times f_{SW} \times L} \quad (1)$$

The current through the bottom MOSFET will ramp to near zero before the next t_{ON} time. When this occurs, the bottom MOSFET turns off, preventing recirculation current that can

seriously reduce efficiency under these light load conditions. As load current is further reduced, the combined feedback and ramp signals remain much higher than the reference voltage, the instant-PWM control loop will not trigger another t_{ON} until needed, and the apparent operating switching frequency will correspondingly drop, improving efficiency. Continuous conduction mode (CCM) resumes smoothly as soon as the load current increases sufficiently for the inductor current to remain above zero at the time of the next t_{ON} cycle. The buck converter enters CCM once the load current exceeds the threshold shown in (1). Above the threshold, the switching frequency stays fairly constant over the output current range.

While in PFM mode, the output of the device doesn't require over voltage protection because the device stops switching as soon as the voltage at the FB node increases above V_{REF} , preventing the output voltage from increasing further.

Input Under Voltage Lockout (UVLO)

To prevent operation before the internal circuitry is ready and to ensure that the top and bottom MOSFETs can be properly driven, the device incorporates an input under voltage lockout protection. The device remains in a low current state and all LX node switching actions are inhibited until V_{IN} exceeds its rising threshold. At that time, if EN is enabled, the device will startup. If V_{IN} falls below $V_{IN,UVLO}$ less than the input UVLO hysteresis, the LX node switching actions will again be suppressed.

Precise EN Threshold

The EN pin uses precise rising and falling thresholds to provide programmable ON/OFF control. The device will be turned on when the EN pin voltage exceeds the rising threshold. The device will be turned off while the EN pin voltage falls below the falling threshold. Increasing the input UVLO threshold is possible using an external resistor divider as shown below:

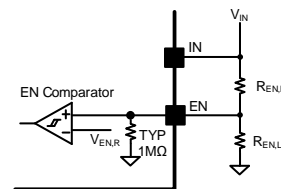


Figure4. Enable Control

It is not recommended to connect EN pin to the V_{IN} or another voltage source directly. A resistor with a value between $1\text{k}\Omega$ and $1\text{M}\Omega$ is recommended if the EN pin is pulled high.

Soft-Start and Startup with Pre-Biased Output

The device incorporates an internal soft-start circuit to ramp the output to the desired voltage whenever the device is

enabled. Internally, the soft-start circuit clamps the output at a low voltage and then allows the output to rise to the desired voltage over approximately 1.5ms, which avoids high current flow and transients during startup.

The device supports startup with pre-biased output. If the output is pre-biased to a certain voltage before startup, the buck converter disables the switching of both the top MOSFET and the bottom MOSFET until the internal soft-start voltage V_{SS} exceeds the sensed output voltage at the FB node. The first pulse on-time is internally calculated based the input voltage and pre-biased output voltage.

External Bootstrap Capacitor

The external bootstrap capacitor provides the gate driver voltage for the N-channel top MOSFET. A 0.1 μ F low ESR ceramic capacitor connected between the BS pin and the LX pin is recommended.

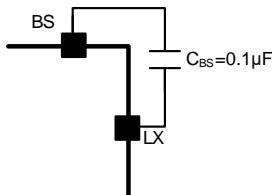


Figure5. Bootstrap Capacitor Connection

Fault Protection Modes

Cycle-by-Cycle Current Limit Protection

If the top MOSFET current exceeds the top current limit threshold, it will turn off and the bottom MOSFET will turn on. If the bottom MOSFET current exceeds the bottom current limit threshold, it will stay on until the current decreases below its current limit threshold. As a result, both inductor peak and valley currents are limited.

Output Under Voltage Protection (UVP)

With output current increasing, as soon as the bottom MOSFET current exceeds its current limit threshold, the top MOSFET will not be allowed to turn on any more. If the load current continues to increase, the output voltage will drop. When the output voltage falls below 33% of the regulated level, the output under voltage protection will be activated and the device will operate in hiccup mode. The hiccup on-time is 2.5ms, and the hiccup off-time is 7.5ms. If the hard short condition is removed, the device will return to normal operation.

Over Temperature Protection (OTP)

The device includes over temperature protection (OTP) circuitry to prevent overheating due to excessive power dissipation. This will shut down the device when the junction temperature exceeds 150°C. When the junction

temperature is reduced by approximately 15°C, the device will resume normal operation after a complete soft-start cycle. For continuous operation, provide adequate thermal dissipation so that the junction temperature does not exceed the OTP threshold.

Application Information

The following paragraphs provide information on the selection of the external components needed to meet the targeted application specifications.

Feedback Resistor Divider R_H and R_L

Choose R_H and R_L to program the proper output voltage. A value between 1k Ω and 1M Ω is recommended for both resistors to minimize power consumption under light loads. As an example, if $V_{OUT} = 3.3V$ and R_H selected value is 100k Ω , R_L can be calculated as follows:

$$R_L = \frac{0.6}{V_{OUT} - 0.6V} \times R_H$$

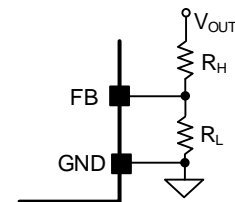


Figure6. Feedback Resistor Divider

With a calculated value of 22.2k Ω for R_L , a standard 1% 22.1k Ω resistor is selected.

Input Capacitor C_{IN}

For the best performance, select a typical X5R or better grade ceramic capacitor with a 25V rating, and at least 10 μ F capacitance. The capacitor should be placed as close as possible to the device, while also minimizing the loop area formed by C_{IN} and the IN/GND pins.

When selecting an input capacitor, ensure that its voltage rating is at least 20% greater than the maximum voltage of the input supply. X5R or X7R dielectric types are the most often selected due to their small size, low cost, surge current capability, and high RMS current rating over a wide temperature and voltage range.

In situations where the input rail is supplied through long wires, it is recommended to add some bulk capacitance like electrolytic, tantalum or polymer type capacitors to reduce the overshoot and ringing caused by the added parasitic inductance.

Consider the RMS current rating of the input capacitor, paralleling additional capacitors if required to meet the

calculated RMS ripple current.

$$I_{CIN_RMS} = I_{OUT} \times \sqrt{D \times (1 - D)}$$

The worst-case condition occurs at $D = 0.5$, then

$$I_{CIN_RMS,MAX} = \frac{I_{OUT}}{2}$$

For simplicity, use an input capacitor with an RMS current rating greater than 50% of the maximum load current. The input capacitor value determines the input voltage ripple of the converter. If there is a voltage ripple requirement in the system, choose an appropriate input capacitor that meets the specification.

Given the very low ESR and ESL of ceramic capacitors, the input voltage ripple can be estimated using the formula:

$$V_{CIN_RIPPLE,CAP} = \frac{I_{OUT}}{f_{SW} \times C_{IN}} \times D \times (1 - D)$$

The worst-case condition occurs at $D = 0.5$, then

$$V_{CIN_RIPPLE,CAP,MAX} = \frac{I_{OUT}}{4 \times f_{SW} \times C_{IN}}$$

The capacitance value is less important than the RMS current rating. A single 10 μ F X5R capacitor is sufficient for most applications.

Output Inductor L

Consider the following when choosing this inductor:

- 1) Choose the inductance to provide a ripple current that is approximately 40% of the maximum output current. The recommended inductance is calculated as:

$$L = \frac{V_{OUT}(1 - V_{OUT}/V_{IN,MAX})}{f_{SW} \times I_{OUT,MAX} \times 0.4}$$

Where, f_{SW} is the switching frequency and $I_{OUT,MAX}$ is the maximum load current.

The device has high tolerance for ripple current amplitude variation. As a result, the final choice of inductance can vary slightly from the calculated value with no significant performance impact.

- 2) The inductor's saturation current rating must be greater than the peak inductor current under full load:

$$I_{SAT,MIN} > I_{OUT,MAX} + \frac{V_{OUT}(1 - V_{OUT}/V_{IN,MAX})}{2 \times f_{SW} \times L}$$

- 3) The DCR of the inductor and the core loss at the switching frequency must be low enough to achieve the

desired efficiency requirement. Use an inductor with DCR less than 30m Ω to achieve good overall efficiency.

Output Capacitor C_{OUT}

Select the output capacitor C_{OUT} to handle the output ripple requirements. Both steady state ripple and transient requirements must be taken into consideration when selecting C_{OUT} . For the best performance, use a X5R or better grade ceramic capacitor with a 16V rating, and capacitance of at least 22 μ F.

For applications where the design must meet stringent ripple requirements, the following considerations must be followed.

The output voltage ripple at the switching frequency is caused by the inductor current ripple (ΔI_L) on the output capacitor's ESR (ESR ripple), as well as the stored charge (capacitive ripple). When calculating total ripple, consider both.

$$V_{RIPPLE,ESR} = \Delta I_L \times ESR$$

$$V_{RIPPLE,CAP} = \frac{\Delta I_L}{8 \times C_{OUT} \times f_{SW}}$$

The measured capacitive ripple might be higher than the theoretical value because the effective capacitance for ceramic capacitors decreases with the voltage across its terminals. The voltage derating is usually included as a chart in the capacitor datasheet, and the ripple can be recalculated after taking the target output voltage into account.

Feedforward Capacitor C_{FF}

The device integrates the compensation components to achieve good stability and fast transient responses. In some applications, adding a ceramic capacitor (feedforward capacitor C_{FF}) in parallel with R_H may further speed up the load transient response. It is recommended at least 10pF for most applications. Note that when the output LC parameter is large, the feedforward capacitor can be increased for providing sufficient ripple to FB for small output ripple and good transient behavior.

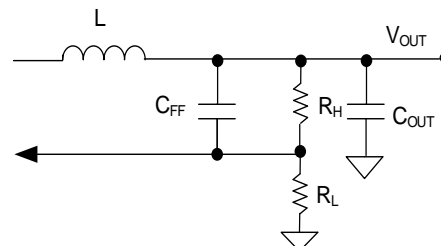


Figure7. Feedforward Network



Application Schematic ($V_{OUT} = 3.3V$)

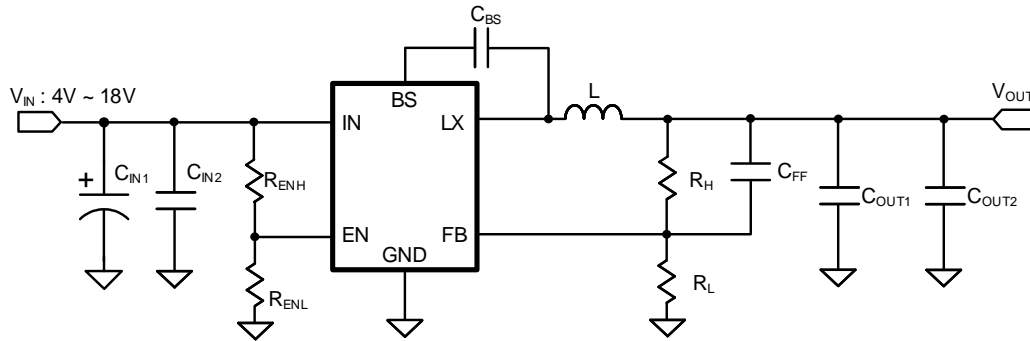


Figure8. Schematic Diagram

BOM List

Reference Designator	Description	Part Number	Manufacturer
C _{IN1}	47μF/50V Electrolytic Capacitor		
C _{IN2}	10μF/25V/X5R, 1206	GRM31CR61E106KA12L	mμRata
C _{OUT1}	22μF/16V/X5R, 1206	GRM31CR61C226ME15L	mμRata
C _{OUT2}	22μF/16V/X5R, 1206	GRM31CR61C226ME15L	mμRata
C _{BS}	0.1μF/50V/X5R, 0603	GRM188R61H104KA93D	mμRata
C _{FF}	220pF/50V/C0G, 0603	GRM1885C1H221JA01D	mμRata
L	2.2μH/inductor, 8.4A	SPM6530T-2R2M	TDK
R _H	100kΩ, 1%, 0603		
R _L	22.1kΩ, 1%, 0603		
R _{ENH}	10kΩ, 1%, 0603		
R _{ENL}	1MΩ, 1%, 0603		

Recommend Component Values for Typical Applications

V _{OUT} (V)	R _H (kΩ)	R _L (kΩ)	C _{FF} (pF)	L/Part Number	C _{OUT}
1.2	100	100	220	1.0μH/SPM6530T-1R0M120	2 × 22μF/16V/X5R, 1206
1.8	100	49.9	220	1.5μH/SPM6530T-1R5M100	2 × 22μF/16V/X5R, 1206
3.3	100	22.1	220	2.2μH/SPM6530T-2R2M	2 × 22μF/16V/X5R, 1206
5	100	13.7	220	3.3μH/SPM6530T-3R3M	2 × 22μF/16V/X5R, 1206

Layout Design

Follow these PCB layout guidelines for optimal performance and thermal dissipation:

Input Capacitors: Place the input capacitors very close to IN and GND pins, minimizing the loop formed by these connections. The input capacitor should be connected to the IN and GND pins using a wide copper area.

Output Capacitors: Connect the C_{OUT} negative terminal to the GND pin using wide copper traces instead of vias, in order to achieve better accuracy and stability of the output voltage.

Feedback Network: Place the feedback components (R_H , R_L and C_{FF}) as close to the FB pin as possible. Avoid routing the feedback line near LX, or other high-frequency signals as it is noise-sensitive. Use a Kelvin connection to connect with C_{OUT} rather than the inductor output terminal.

LX Connection: Keep the LX area small to prevent excessive EMI, while providing a wide copper trace to minimize parasitic resistance and inductance.

BS Capacitor and Resistor: Place the BS capacitor on the same layer as the device, keep the BS voltage path (BS, LX and C_{BS}) as short as possible.

EN Signal: It is not recommended to connect EN pin directly to V_{IN} or another voltage source. A resistor in a range of $1k\Omega$ to $1M\Omega$ should be used if EN pin is pulled high.

GND Vias: Place an adequate number of vias on the GND layer around the device for better thermal performance. The exposed GND pad should be connected to a copper area larger than its size. Place multiple GND vias on it for heat dissipation.

PCB Board: To achieve the best thermal and noise performance, maximize the PCB copper area connecting to the GND pin. A ground plane is highly recommended if possible. Connect the ground pad to a large copper area to enhance thermal performance.

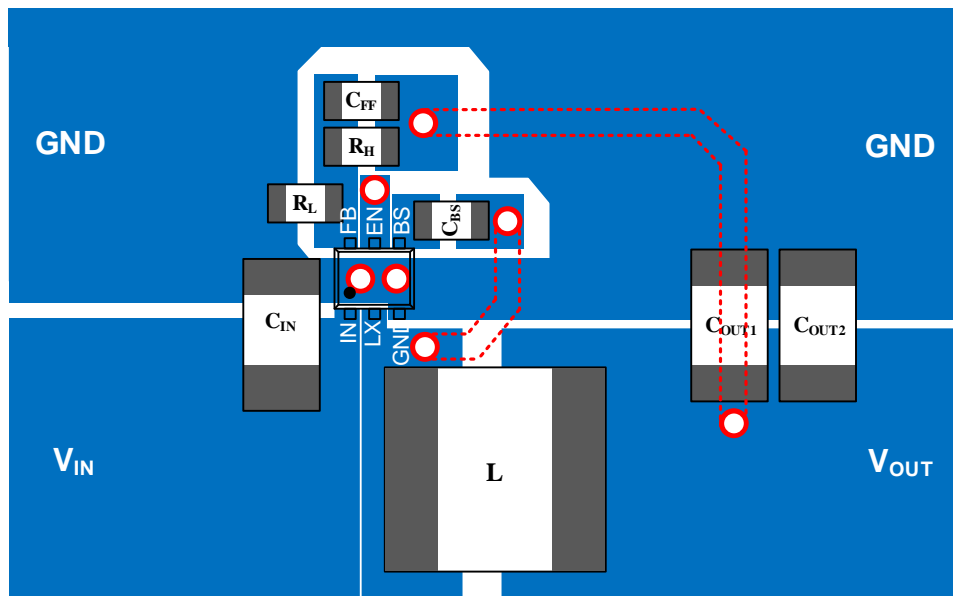
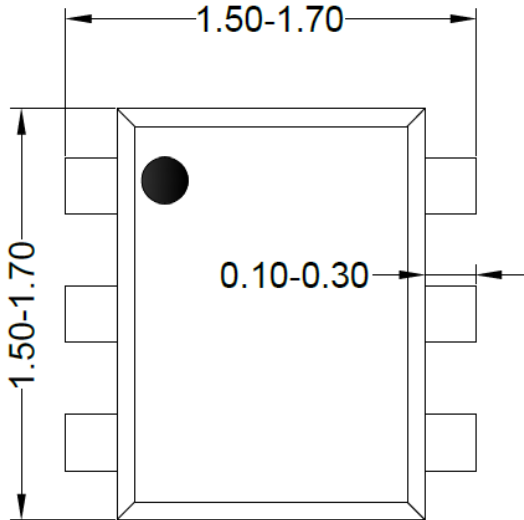
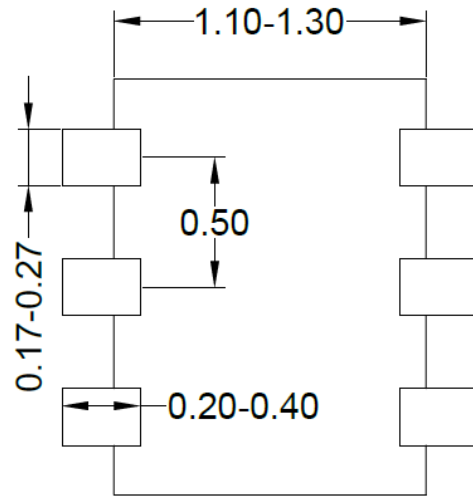


Figure9. Suggested PCB Layout

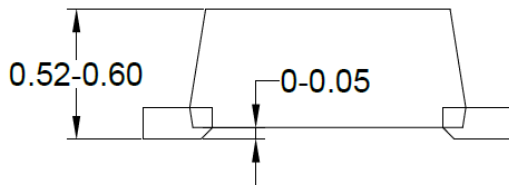
SOT563 Package Outline Drawing



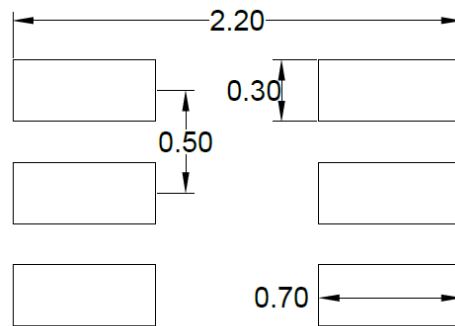
Top view



Bottom view



Side View

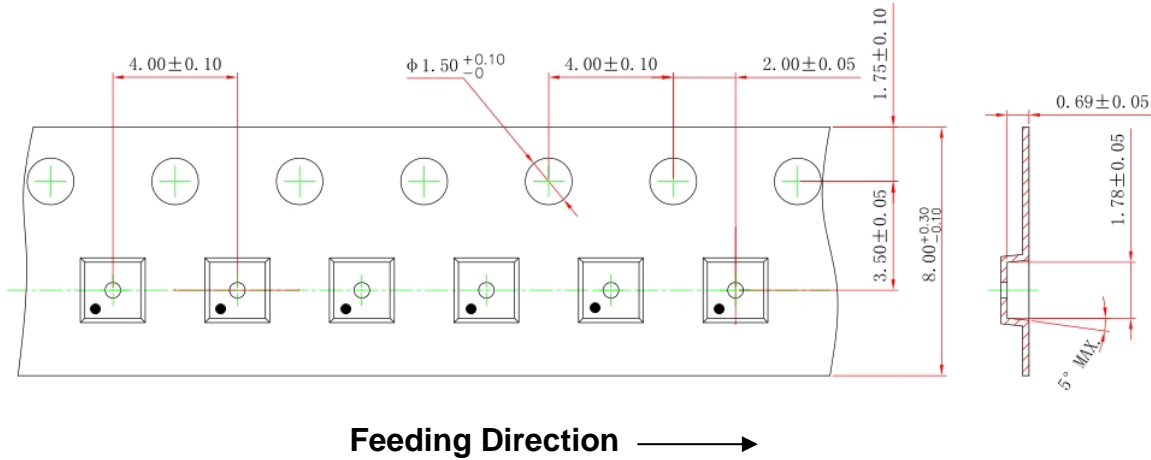


**Recommended PCB layout
(Reference only)**

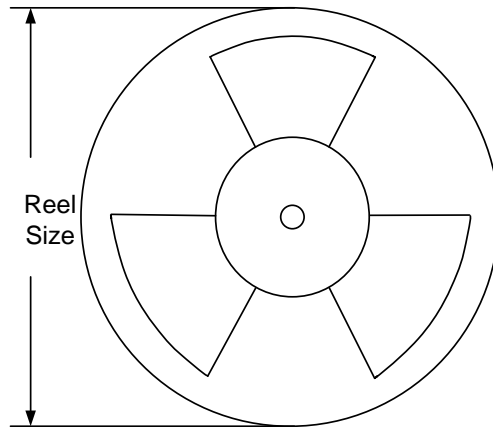
Notes: All dimension in millimeter and exclude mold flash & metal burr.

Taping and Reel Specification

1. Taping Orientation SOT563



2. Carrier Tape and Reel Specification for Packages



Package types	Tape width (mm)	Pocket pitch(mm)	Reel size (Inch)	Trailer length(mm)	Leader length (mm)	Qty per reel (pcs)
SOT563	8	4	7	280	160	5000



Revision History

The revision history provided is for informational purpose only and is believed to be accurate, however, not warranted. Please make sure that you have the latest revision.

Date	Revision	Change	Pages changed
Jun.23, 2025	1.0	Initial Release.	-

IMPORTANT NOTICE

1. **Right to make changes.** Silergy and its subsidiaries (hereafter Silergy) reserve the right to change any information published in this document, including but not limited to circuitry, specification and/or product design, manufacturing or descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products are sold subject to Silergy's standard terms and conditions of sale.
2. **Applications.** Application examples that are described herein for any of these products are for illustrative purposes only. Silergy makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification. Buyers are responsible for the design and operation of their applications and products using Silergy products. Silergy or its subsidiaries assume no liability for any application assistance or designs of customer products. It is customer's sole responsibility to determine whether the Silergy product is suitable and fit for the customer's applications and products planned. To minimize the risks associated with customer's products and applications, customer should provide adequate design and operating safeguards. Customer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Silergy assumes no liability related to any default, damage, costs or problem in the customer's applications or products, or the application or use by customer's third-party buyers. Customer will fully indemnify Silergy, its subsidiaries, and their representatives against any damages arising out of the use of any Silergy components in safety-critical applications. It is also buyers' sole responsibility to warrant and guarantee that any intellectual property rights of a third party are not infringed upon when integrating Silergy products into any application. Silergy assumes no responsibility for any said applications or for any use of any circuitry other than circuitry entirely embodied in a Silergy product.
3. **Limited warranty and liability.** Information furnished by Silergy in this document is believed to be accurate and reliable. However, Silergy makes no representation or warranty, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. In no event shall Silergy be liable for any indirect, incidental, punitive, special or consequential damages, including but not limited to lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges, whether or not such damages are based on tort or negligence, warranty, breach of contract or any other legal theory. Notwithstanding any damages that customer might incur for any reason whatsoever, Silergy' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Standard Terms and Conditions of Sale of Silergy.
4. **Suitability for use.** Customer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of Silergy components in its applications, notwithstanding any applications-related information or support that may be provided by Silergy. Silergy products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of Silergy product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Silergy assumes no liability for inclusion and/or use of Silergy products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.
5. **Terms and conditions of commercial sale.** Silergy products are sold subject to the standard terms and conditions of commercial sale, as published at <http://www.silergy.com/stdterms>, unless otherwise agreed in a valid written individual agreement specifically agreed to in writing by an authorized officer of Silergy. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Silergy hereby expressly objects to and denies the application of any customer's general terms and conditions with regard to the purchase of Silergy products by the customer.
6. **No offer to sell or license.** Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights. Silergy makes no representation or warranty that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right. Information published by Silergy regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from Silergy under the patents or other intellectual property of Silergy.

For more information, please visit: www.silergy.com

© 2025 Silergy Corp.

All Rights Reserved.